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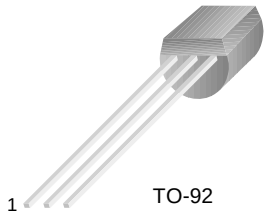
PN3568

NPN General Purpose Amplifier

- This device is designed for general purpose, medium power amplifiers and switches requiring collector currents to 500mA.



TO-92

1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5.0	V
I_C	Collector Current - Continuous	1.0	A
$T_{J,}$ T_{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaird.

NOTES:
1. These ratings are based on a maximum junction temperature of 150 degrees C.
2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage *	I_C = 30mA, I_B = 0	60		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 100µA, I_E = 0	80		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10µA, I_C = 0	5.0		V
I_{CBO}	Collector Cut-off Current	V_{CB} = 40V, I_E = 0 V_{CB} = 40V, I_E = 0, T_A = 75°C		50 5.0	nA µA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 4V, I_C = 0		25	nA
On Characteristics					
h_{FE}	DC Current Gain	V_{CE} = 1.0V, I_C = 30mA V_{CE} = 1.0V, I_C = 150mA	40 40	 120	
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 150mA, I_B = 15mA		0.25	V
V_{BE}(on)	Base-Emitter On Voltage	V_{CE} = 1.0V, I_C = 150mA		1.1	V
Small Signal Characteristics					
C_{ob}	Output Capacitance	V_{CB} = 10V, f = 1.0MHz		20	pF
C_{ib}	Input Capacitance	V_{EB} = 0.5V, f = 1.0MHz		80	
h_{fe}	Small Signal Current Gain	I_C = 50mA, V_{CE} = 10V, f = 20MHz	3.0	30	

* Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

Package Dimensions

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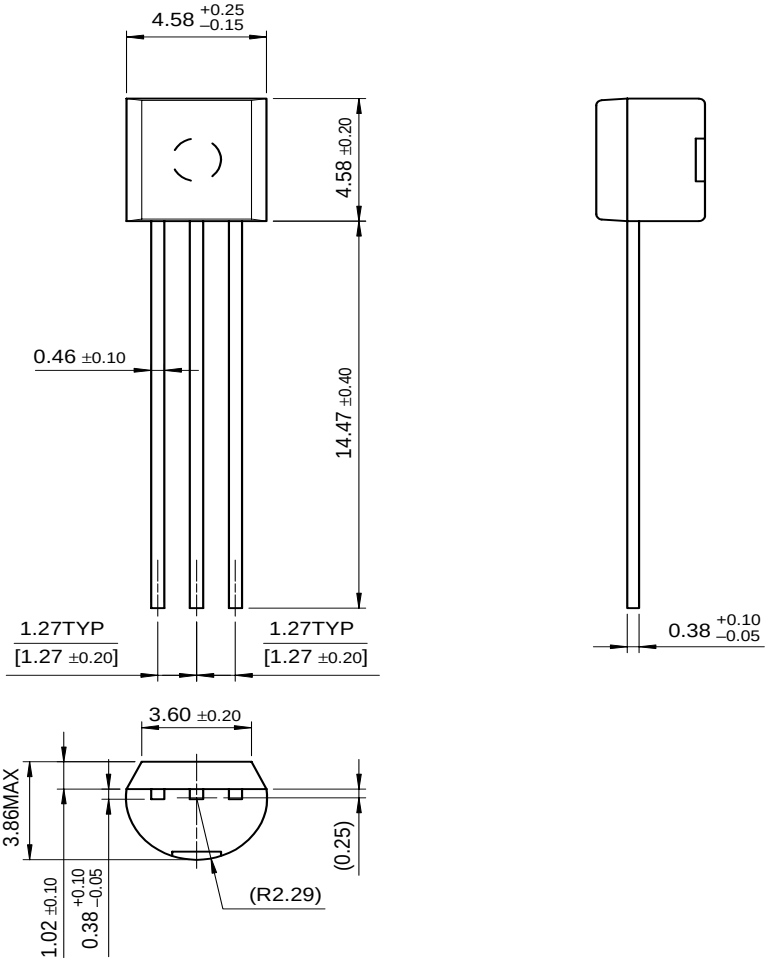

Dimensions in Millimeters

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